**TELEFUNKEN Semiconductors** 

## Timing Processor (LINE, FRAME, SMPS) for TV Sets

### **General Description**

This integrated circuit uses I<sup>2</sup>L bipolar technology and combines analog signal processing with digital processing. Timing signals are obtained from a Voltage-Controlled Oscillator (VCO) operating at 500 kHz by means of a cheap ceramic resonator.

A chain of dividers and appropriate logic functions are producing very accurately defined sampling pulses and the necessary timing signals. This avoids the frequency adjustment normally required with line and frame oscillators.

#### **Features**

- 500 kHz VCO and appropriate logic avoids adjustment of timing pulses
- Identical line and Switch Mode Power Supply (SMPS) frequency avoids visible interference on
- Multistandard capability by automatic 50/60 Hz identification
- Low power dissipation by controlling a frame thyristor (or class D output transistor stage)
- Video identification circuit
- Super sandcastle

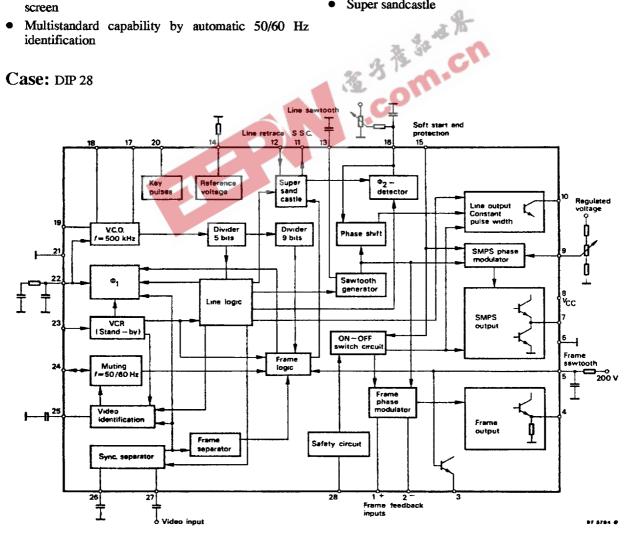


Figure 1. Block diagram

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### **Absolute Maximum Ratings**

 $T_{amb} = 25$ °C, unless otherwise specified.

Parameter		Symbol	Value	Unit
Supply voltage	Pin 8	$V_{S}$	14	V
AGC current	Pin 20	I <sub>20</sub>	5	mA
Video identification current	Pin 24	I <sub>24</sub>	10	mA
Line retrace current Line output current	Pin 12 Pin 10	$\begin{array}{c c} \pm I_{12} \\ +I_{10} \\ -I_{10} \end{array}$	10 40 10	mA
Frame sawtooth generator	Pin 3	I <sub>S</sub>	20	mA
Frame output current	Pin 4	I <sub>4</sub>	100	mA
SMPS output current	Pin 7	± I <sub>7</sub>	50	mA
Safety input current	Pin 28	I <sub>28</sub>	5	mA
Safety input voltage	Pin 28	V <sub>28</sub>	$V_{CC}$	
Ambient temperature range		T <sub>amb</sub>	0 to +70	°C
Storage temperature range		T <sub>stg</sub>	-25 to +150	°C

### **Thermal Resistance**

Parameters	Symbol	Value	Unit
Junction ambient	$R_{thJA}$	55	K/W

### **Electrical Characteristics**

 $V_S = V_{CC} = 12 \text{ V}, T_{amb} = 25 ^{\circ}\text{C}, \text{ unless otherwise specified}$ 

Parameters	Test Conditions /	Pins	Symbol	Min.	Typ.	Max	Unit
Supply current	Frame, line and SMI output without load		$I_S$		60	80	mA
Sync. separator		Pins 26 a	nd 27				
Positive video input signal, ac coupled	Source impedance ≤ 200 Ω	Pin 27	V <sub>27</sub>	0.2	1.8	3	V <sub>pp</sub>
Negative clamping current during sync. pulse			-I <sub>27</sub>	25	40	55	μΑ
Clamping current, continuously			I <sub>27</sub>	3	5	9	μΑ
Slicing level decoupling	Negative current	Pin 26	-I <sub>26</sub>		640	1000	μA
50 % of sync. amplitude	Positive current		I <sub>26</sub>	12	25	36	μΑ
Pulse for keyed AGC		Pin 20		···			·
Output current			$\overline{I_0}$			5	mA
Output separation voltage	$I_0 = 5 \text{ mA}$		$V_0$			0.4	V
Delay time from the key pul- middle of the sync. pulse	se leading edge to the		t <sub>d1</sub>		3.4		μs
Delay time from the middle pulse trailing	of the sync. pulse to th	e key	t <sub>d2</sub>		4.8		μs

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Parameters	Test Conditions			Min.	Тур	Max.	Unit
Voltage control oscillator, V		Pin 17, 1		·			
$V_S = V_{CC} = 11 \text{ V to } 13 \text{ V}$	Ceramic resonator t	ype: CSB	503 B				
Operating voltage		Pin 8	$V_{S}$	5		13.2	V
Frequency control range	Low-end		$f_{low}$		15.3		kHz
after H. divider	High-end		$\mathbf{f_{high}}$		16.1		<u> </u>
Control current		Pin 22	$\pm I_{22}$			10	μA
Phase detector $\emptyset_1$		Pin 22					
Output current	Low loop gain		± I <sub>0</sub>	0.35	0.5	0.65	mA
	High loop gain			1	1.5	2	
Ratio of charging and			$I_{ch}/I_{dis}$		1		
discharging current							
Transfer gain	Low loop gain		$G_{TL}$		1.2		kHz/μs
	High loop gain		$G_{TH}$		3.6		
Window pulse width			tØ1		10		μs
(only in low loop gain, video							
Delay time between middle	of key pulse and $\emptyset_1$ c	ompar-	t <sub>d</sub>		<b>3</b> _0		μs
ison edge				1	10		<u> </u>
VCR and STAND-BY swit		Pin 23		3. 34			
Threshold voltage VCR (VC	R switch is in ON po	osition	$V_{\mathrm{T}}$	1.6	2.1	2.6	V
below this value)			92 4)	- 401			
Threshold voltage STAND-I			$V_{T}$	3.2	4	4.8	V
(STAND-BY switch is in Ol	N position above this	level)	<u> </u>				
Input current			$-I_1$	0.030		1	mA
Video identification, see fig	gure 2	Pins 24					
Input current		Pin 24	$I_{\mathrm{I}}$			10	mA
Output saturation voltage	$I_I = 5 \text{ mA}$ , no video	o sign <b>al</b>	$V_{Osat}$			0.6	V
Output voltage	f = 60  Hz,	Pin 24	$V_0$	5.5	6	7.5	V
	$I_{i(Video)} = 2.5 \text{ mA}$						
Input current	f = 50 Hz	Pin 24	$\mathbf{I_{I}}$			10	μA
Output current,		Pin 25	$I_{ch}$	0.5	0.75	1	mA
charging the capacitor							
Ratio between the charg-		Pin 25	$I_{ch}/I_{dis}$	1.7		4.0	
ing and discharging current							
Identification sampling		Pin 25	t <sub>25</sub>	1.3		2.2	μs
time							
Threshold voltage		Pin 25					
	lower to higher val		$V_{\mathrm{T}}$	4	4.5	5	V
	(low means no vide						
Hysteresis voltage	<u> </u>	Pin 25	V <sub>hyst</sub>	<u> </u>	350		mV
H. ramp generator, see fig	<del>,                                    </del>	Pin 13			-		<b>,</b>
Saw-tooth amplitude	peak to peak	<del></del>	v	3	3.5	4	V
synchronized state				ļ			
Charge current			$I_{ch}$	185	200	215	μA
Saw-tooth base voltage			$V_{min}$			0.5	V
Discharging time			t <sub>dis</sub>			4	μs
Delay time between $\emptyset_2$ com	paring edge and lead	ing	t <sub>d</sub>		1.95		μs
edge of discharging pulse				J			,

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Super sandcastle, SSC   Output current   Output current   Output voltage levels; I11 = 5 mA   Burst key pulse   Horizontal blank pulse   Frame blank pulse   I11 = 5 mA   Frame blank pulse   I11 = 5 mA   I11 = 5 m	Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Output voltage levels: Burst key pulse Burst key pulse Horizontal blank pulse Frame blank pulse Delay time between middle of sync. pulse (pin 27) and leading edge of burst key pulse Duration of burst key pulse Duration of burst key pulse Delay time  between SSC cutting level at pin 12 and line blank pulse Frame retrace blanking duration  Line retrace input First threshold for blanking Second threshold for $\theta_2$ V <sub>12</sub> = 12 V V <sub>12</sub> = 5 V V <sub>12</sub> = 5 V V <sub>12</sub> = 1 V Phase detector $\theta_2$ Charging current  Ratio of charging and discharging current Delay time between the comparing edges of $\theta_1$ and $\theta_2$ for (VCO) = 500 kHz Imput current of internal error amplifier for $\theta_2$ phase shift Time difference between $\theta_2$ comparing edge and middle of line retrace (without external phase tuning circuit) Horizontal output (Open collector). Pin 10 Output saturation voltage V <sub>1</sub> = 20 mA V <sub>2</sub> V <sub>1</sub> = 24 V <sub>2</sub> 26 V <sub>3</sub> 28 V <sub>4</sub> V <sub>5</sub> 27 V <sub>5</sub> 28 V <sub>5</sub> 28 V <sub>5</sub>	Super sandcastle, SSC	Pin 11					10.00
Output voltage levels;   I11 = 5 mA   VBurst   9	Output current		I <sub>11</sub>	-10		+ 10	mA
Horizontal blank pulse	Output voltage levels;	$I_{11} = 5 \text{ mA}$					1
Horizontal blank pulse   I <sub>1</sub> = 5mA   I <sub>2</sub> = 5mA   I <sub>3</sub> = 5mA   I <sub>4</sub> = 5mA   I <sub></sub>			$V_{\mathrm{Burst}}$				v
Frame out of function   Comparing edges of burst key pulse   Duration of burst key pulse   Delay time   between SSC cutting   level at pin 12 and line   blank pulse   Duration of burst key pulse   Delay time   between SSC cutting   level at pin 12 and line   blank pulse   Duration of burst key pulse   Delay time				4	4.5	5	
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Frame blank pulse		$V_{VB}$	2	2.5	3	V
Duration of burst key pulse   Delay time   Delay time bunk pulse   Delay time bun			t <sub>d</sub>	2.3		3	μs
Delay time   between SSC cutting level at pin 12 and line blank pulse   24   lines		186		2.7		<i>E</i>	
level at pin 12 and line blank pulse		hoterion SSC outting		3.7	4		<del>                                     </del>
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Delay time	level at pin 12 and line	<sup>L</sup> d			0.5	μs
First threshold for blanking Second threshold for $\emptyset_2$ V <sub>02</sub> 11 1.3 2.3 V Input currents: $V_{12} = 12 \text{ V}$ $V_{02} = -1$ 1.3 2.3 V Input currents: $V_{12} = 5 \text{ V}$ $V_{12} = 5 \text{ V}$ $V_{12} = 5 \text{ V}$ $V_{12} = 0 \text{ V}$ $V_{12} = 1 \text{ V}$ $V_{13} = 1 \text{ V}$ $V_{14} = 1 \text{ V}$ $V_{14} = 1 \text{ V}$ $V_{15} = 1 \text$	Frame retrace blanking duration				24		lines
First threshold for blanking Second threshold for $\emptyset_2$ V <sub>02</sub> 11 1.3 2.3 V Input currents: $V_{12} = 12 \text{ V}$ $V_{02} = -1$ 1.3 2.3 V Input currents: $V_{12} = 5 \text{ V}$ $V_{12} = 5 \text{ V}$ $V_{12} = 5 \text{ V}$ $V_{12} = 0 \text{ V}$ $V_{12} = 1 \text{ V}$ $V_{13} = 1 \text{ V}$ $V_{14} = 1 \text{ V}$ $V_{14} = 1 \text{ V}$ $V_{15} = 1 \text$	Line retrace input	Pin 12	·	•			·
Second threshold for $\emptyset_2$			V <sub>h</sub>	11	3 15	12	V
Input currents: $\begin{array}{c ccccccccccccccccccccccccccccccccccc$				-1 %	1.3		
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		V <sub>12</sub> =12 V		4.19			<del> </del>
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	•		36	25			
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$			1,38		-50		
Phase detector $\theta 2$ ,       Pin 16         Charging current $I_{ch}$ $0.4$ $0.6$ $0.8$ mA         Ratio of charging and discharging current $I_{ch}/I_{dis}$ 1           Delay time between the comparing edges of $\theta_1$ and $\theta_2$ for $(VCO) = 500 \text{ kHz}$ $I_{ch}/I_{dis}$ 1.5       2       2.8       μs         Input current of internal error amplifier for $\theta_2$ phase shift $I_{16}$ 3       μA         Time difference between $\theta_2$ comparing edge and middle of line retrace (without external phase tuning circuit) $\Delta t$ 0       μs         Horizontal output (Open collector).       Pin 10 $\Delta t$ 0       μs         Output saturation voltage $I_0 = 20 \text{ mA}$ $V_0$ $\Delta t$		$V_{12} = 1 V$		-2	-1		mA
Charging current	Operating input voltage		-V <sub>12</sub>			1	V
Ratio of charging and discharging current  Delay time between the comparing edges of $\emptyset_1$ and $\emptyset_2$ td 1.5 2 2.8 $\mu$ s $f_0$ (VCO) = 500 kHz  Input current of internal error amplifier for $\emptyset_2$ phase shift  Time difference between $\emptyset_2$ comparing edge and middle of line retrace (without external phase tuning circuit)  Horizontal output (Open collector), Pin 10  Output saturation voltage $I_0 = 20 \text{ mA}$ $V_0$ 1 V  Output current $I_0$ 40 mA  Output pulse duration $f_0 = 500 \text{ kHz}$ $f_0 = 20 \text{ mA}$ $f_0$ $f_0 = 20 \text{ mA}$ $f_0 = $	Phase detector Ø2,	Pin 16					
discharging current  Delay time between the comparing edges of $\emptyset_1$ and $\emptyset_2$ $f_0$ (VCO) = 500 kHz  Input current of internal error amplifier for $\emptyset_2$ phase shift  Time difference between $\emptyset_2$ comparing edge and middle of line retrace (without external phase tuning circuit)  Horizontal output (Open collector), Pin 10  Output saturation voltage $I_0 = 20 \text{ mA}$ $V_0$ $I_0$ $I_$			I <sub>ch</sub>	0.4	0.6	0.8	mA
$ f_{0} (VCO) = 500 \text{ kHz} $ Input current of internal error amplifier for $\emptyset_{2}$ phase shift  Time difference between $\emptyset_{2}$ comparing edge and middle of line retrace (without external phase tuning circuit)  Horizontal output (Open collector), Pin 10  Output saturation voltage $I_{0} = 20 \text{ mA}$ $V_{0}$ $I$ $V$ Output current $I_{0}$	Ratio of charging and discharging current		I <sub>ch</sub> /I <sub>dis</sub>		1		
shift  Time difference between $\emptyset_2$ comparing edge and middle of line retrace (without external phase tuning circuit)  Horizontal output (Open collector), Pin 10  Output saturation voltage $I_0 = 20 \text{ mA}$ $V_0$ $I_0$	Delay time between the com $f_o$ (VCO) = 500 kHz	paring edges of $\emptyset_1$ and $\emptyset_2$	t <sub>d</sub>	1.5	2	2.8	μs
of line retrace (without external phase tuning circuit)  Horizontal output (Open collector), Pin 10  Output saturation voltage $I_0 = 20 \text{ mA}$ $V_0$ $I_0$ $V_0$ $I_0$	Input current of internal erroshift	r amplifier for $\emptyset_2$ phase	I <sub>16</sub>			3	μА
of line retrace (without external phase tuning circuit)  Horizontal output (Open collector), Pin 10  Output saturation voltage $I_0 = 20 \text{ mA}$ $V_0$ $I_0$ $V_0$ $I_0$	Time difference between $\emptyset_2$	comparing edge and middle	Δt		0		US
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$							μο
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Horizontal output (Open co	ollector), Pin 10	<u> </u>				<del></del>
Output pulse duration $f_0 = 500 \text{ kHz}$ $t_p$ 24 26 28 $\mu s$ $\theta_2$ phase range without external phase shift $t_0$ 14 16 19 $\mu s$ Frame logic  Free running period video identification = 0 N 315 lines identification = 0 N 347 361 lines 50 Hz window N 309 315 lines 60 Hz window N 247 277 lines VCR mode window N 247 361 lines	Output saturation voltage	Y	V <sub>0</sub>			1	V
$ θ_2 $ phase range without external phase shift $ t_0 $ 14 16 19 $ μs $ Frame logic  Free running period video identification = 0  Search window N 247 361 lines 50 Hz window N 309 315 lines 60 Hz window N 247 277 lines VCR mode window N 247 361 lines	Output current		I <sub>0</sub>			40	mA
shift           Frame logic           Free running period video identification = 0         N         315         lines           Search window         N         247         361         lines           50 Hz window         N         309         315         lines           60 Hz window         N         247         277         lines           VCR mode window         N         247         361         lines	Output pulse duration	$f_0 = 500 \text{ kHz}$	t <sub>p</sub>	24	26	28	μs
Free running period video identification = 0         N         315         lines           Search window         N         247         361         lines           50 Hz window         N         309         315         lines           60 Hz window         N         247         277         lines           VCR mode window         N         247         361         lines	$\emptyset_2$ phase range		tø	14	16	19	μs
Free running period video identification = 0         N         315         lines           Search window         N         247         361         lines           50 Hz window         N         309         315         lines           60 Hz window         N         247         277         lines           VCR mode window         N         247         361         lines	Frame logic			·	l		1
50 Hz window         N         309         315         lines           60 Hz window         N         247         277         lines           VCR mode window         N         247         361         lines	Free running period video identification = 0		N		315		lines
50 Hz window         N         309         315         lines           60 Hz window         N         247         277         lines           VCR mode window         N         247         361         lines	Search window		N	247		361	lines
60 Hz window         N         247         277         lines           VCR mode window         N         247         361         lines	50 Hz window		<del></del>				
VCR mode window N 247 361 lines	60 Hz window		<del></del>	<del> </del>			
	VCR mode window		<del>                                     </del>	<del> </del>			
	Frame saw-tooth generator	*	Pin 5	<u>* l</u>	1		

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Parameters	Test Conditions / Pin	s Symbol	Min.	Тур	Max.	Unit
Saw-tooth amplitude	peak to peak	v	2	3	4	V
60 Hz internal current		$\mathbf{I_0}$	12	14	16	μΑ
generator						
Discharge time	$C = 0.47 \mu F, \Delta V_C = 4 V$				70	μs
Delay time	between beginning of di charging and leading ed- of the first main equaliz ing pulse which appears during internal sync. pul	ge -		5		μs
Saw tooth base voltage	$I_3 = 0.$ to $10 \text{ mA}$ Pin	$V_{\min}$	1	1.26	1.4	V
Frame feed back inputs	Pin	s 1 and 2				
Input current		I <sub>1,2</sub>			10	μΑ
Common mode range		CMR	2		10	V
Frame output, see figure 4	Pin	4				
Operating output current		-I <sub>0</sub>		4	80	mA
Limit value		-I <sub>0M</sub>	i ai	, JD	100	mA
Max. "ON" time		t <sub>on</sub>	3c 34	40		μs
Output phase range		tø	0	0	tonmax	μs
Negative over current	limit value	$I_{NO}$	400	10		mA
Output voltage	$I_4 = -80 \text{ mA}$	V <sub>O</sub>	10			V
Switch mode power supply	, SMPS					
Input current	Pin	9 I <sub>I</sub>			10	μA
Internal reference voltage		V <sub>ref</sub>	1.2	1.26	1.35	V
SMPS Output, see figure 5	Pin	7				
Output current limit value		$I_0$	-50		50	mA
Output voltage	$I_0 = -20 \text{ mA}$ $I_0 = +20 \text{ mA}$	V <sub>0</sub>	10		2	V
t <sub>on</sub> time		tonmax	27	28	29	μs
Position of trailing edge of SMPS pulse				before midd I sync. pulse		
Negative over current limit v	alue	$I_{NO}$			50	mA
Safety input,	Pin					
Threshold voltage		$V_{\rm T}$	1.15	1.26	1.37	V
Input current	$V_T = V_{ref}$	I <sub>I</sub>			3	μA
Input voltage		V <sub>28max</sub>			$V_{CC}$	
Soft starting input and SMI	PS - T <sub>"ON"</sub> limitation (see		5	-		
Charging current	$t = 4 \mu s$	I <sub>ch</sub>	70		130	μΑ
Ratio of charging and discharging current		I <sub>ch</sub> / I <sub>dis</sub>		1		
Charging time		t <sub>ch</sub>		4		μs
Ratio of charging and dis- charging time		t <sub>ch</sub> /t <sub>dis</sub>		2		

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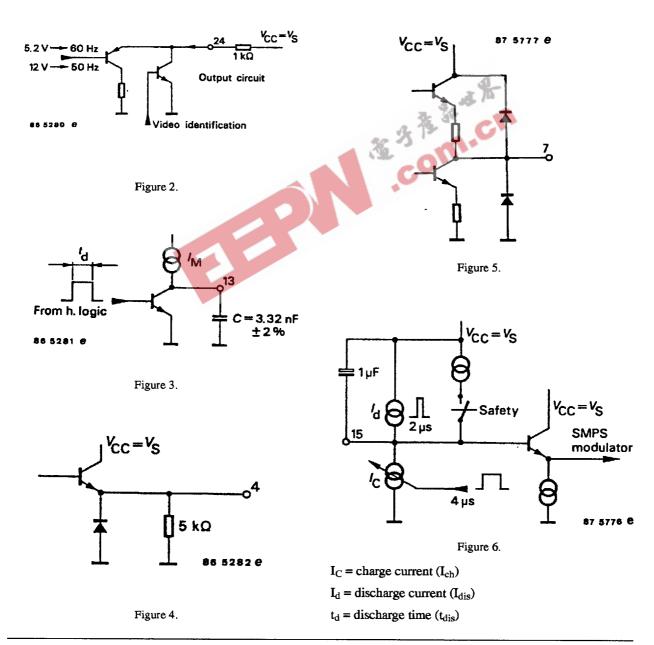
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Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Umit
Switch-ON, Switch-OFF p						
SMPS	frame and line $V_{CC}$ starting	Vs	5.25 + V <sub>hyst</sub>		6.5 + V <sub>hyst</sub>	V
	V <sub>CC</sub> stopping		5.25		6.25	
Hysteresis between switch on- and off level		$V_{hyst}$		500		mV
Voltage reference	Pin 14	V <sub>ref</sub>	1.2	1.26	1.35	V



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### **TELEFUNKEN Semiconductors**

### **Application**

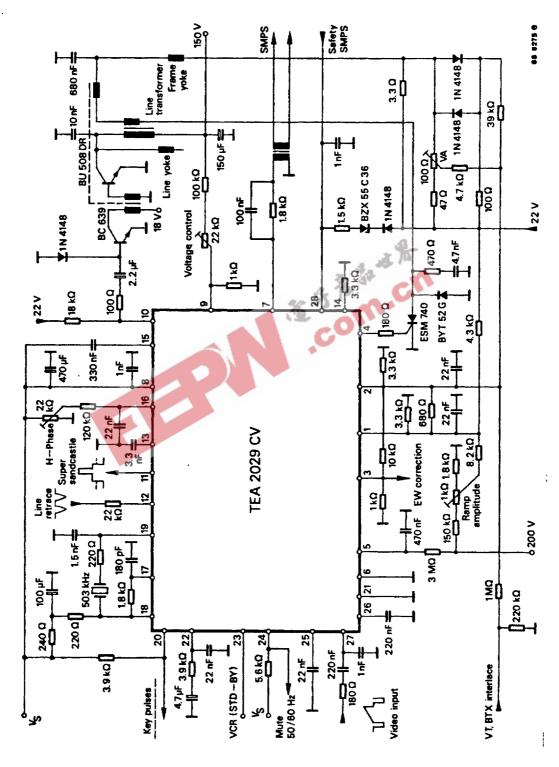


Figure 7.

## **TEA2029CV**

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### **Dimension in mm**

Package: DIP 28

